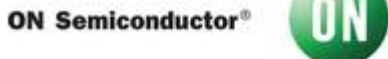
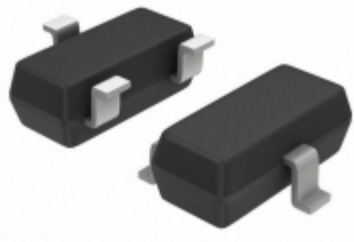









| | |
|---|--|
|  | <h2 style="color: red;">MUN2213JT1</h2> |
|  | <p>Hersteller-Teilenummer: MUN2213JT1</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS NPN 338MW SC59</p> <p>RoHs Status: Enthält Blei / RoHS nicht konform</p> <p>Lagerzustand: New original, 60000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|---|--|
| Teilenummer | MUN2213JT1 |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | TRANS PREBIAS NPN 338MW SC59 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-Bipolar |
| Teilstatus | 60000 pcs Stock |
| Serie | - |
| Befestigungsart | Surface Mount |
| Leistung - max | 338mW |
| Verpackung / Gehäuse | TO-236-3, SC-59, SOT-23-3 |
| Supplier Device-Gehäuse | SC-59 |
| Transistor-Typ | NPN - Pre-Biased |
| Strom - Kollektor (Ic) (max) | 100mA |
| Spannung - Kollektor-Emitter-Durchbruch (max) | 50V |
| VCE Sättigung (Max) @ Ib, Ic | 250mV @ 300µA, 10mA |
| Strom - Collector Cutoff (Max) | 500nA |
| DC Stromgewinn (HFE) (Min) @ Ic, VCE | 80 @ 5mA, 10V |
| Frequenz - Übergang | - |
| Widerstand - Base (R1) (Ohm) | 47k |
| Widerstand - Emitter-Basis (R2) (Ohm) | 47k |
| Verpackung | Tape & Reel (TR) |

MUN2213JT1 ist neu im Original, Suche MUN2213JT1 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie MUN2213JT1 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage MUN2213JT1: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|--|---|---|
|  MUN2212LT1 ON MUN2212LT1 ON |  MUN2213T1 ON MUN2213T1 ON |  MUN2212 ON MUN2212 ON |  MUN2212T1 AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 338MW SC59 |
|  MUN2213LT1G ON ON SOT23 |  MUN2213T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 338MW SC59 |  MUN2212T1G AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 338MW SC59 |  MUN2213 ON ON SOT-23 |

heiße Teile

Mehr

- | | | | | |
|---------------------|------------------|---------------|----------------|-----------------|
| ⊗ LP3927ILQ-AZ/NOPB | ↔ LQH88PN3R3N38L | ⇒ MUN2111LT1 | D MUN2111T1 | ↕ MUN2111T1G |
| ⊣ MUN2112LT1G | ⊗ MUN2112T1 | D MUN2112T1G | ⇒ MUN2113T1 | ↕ MUN2113T1G |
| ⊗ MUN2113XLT1 | ⊣ MUN2114T1 | ⊗ MUN2114T1G | ↔ MUN2115T1 | ↕ MUN2116T1 |
| D MUN2116T1G | ⊗ MUN2132T1 | ⊣ MUN2133T1 | ⊗ MUN2211T1 | ↕ MUN2211T1B |
| ⇒ MUN2211T1G | ↔ MUN2211T1G/3G | ⊗ MUN2211T3G | ⊣ MUN2212LT1 | ↕ MUN2212T1 |
| ↔ MUN2212T1G | ⇒ MUN2213JT1G | D MUN2213T1 | ⊗ MUN2213T1G | ⊣ MUN2214T1G |
| ⊗ MUN2215LT1 | D MUN2215LT1G | ⇒ MUN2215T1 | ↔ MUN2215T1G | ↕ MUN2216T1 |
| ⊣ MUN2216T1G | ⊗ MUN2232T1G | ↔ MUN2233LT1G | ⇒ MUN2233RT1 | ↕ MUN2233T1G |
| ⊗ MUN2234T1G | ⊣ MUN2237T1 | ⊗ MUN2237T1G | D MUN5113T1G | ↕ MUN5114T1G |
| ↔ MUN5115DW1T1G | ⊗ MUN5213T1 | ⊣ MUN5215T1G | ⊗ MUN5312DW1T2 | ↕ MUN5313DW1T1G |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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